

P-CHANNEL ENHANCEMENT MODE MOSFET

Features

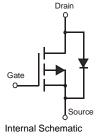
- Low On-Resistance
 - $60m\Omega$ @ $V_{GS} = -4.5V$
 - $90m\Omega @ V_{GS} = -2.5V$
 - $113m\Omega$ @ $V_{GS} = -1.8V$
- Low Input Capacitance
- Fast Switching Speed
- Low Input/Output Leakage
- Lead Free By Design/RoHS Compliant (Note 1)
- "Green" Device (Note 2)
- Qualified to AEC-Q101 Standards for High Reliability

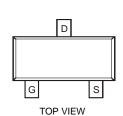
Mechanical Data

- Case: SOT-23
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020D
- Terminals: Finish Matte Tin annealed over Copper leadframe.
 Solderable per MIL-STD-202, Method 208
- Terminals Connections: See Diagram Below
- Marking Information: See Page 4
- Ordering Information: See Page 4
- Weight: 0.008 grams (approximate)



TOP VIEW





Maximum Ratings @T_A = 25°C unless otherwise specified

Characte	eristic		Symbol	Value	Units
Drain-Source Voltage			V _{DSS}	-20	V
Gate-Source Voltage		V _{GSS}	±8	V	
Continuous Drain Current (Note 3)	Steady State	T _A = 25°C T _A = 70°C	I _D	-4.2 -3.4	А
Pulsed Drain Current (Note 4)			I _{DM}	-10	Α

Thermal Characteristics

Characteristic	Symbol	Value	Unit
Power Dissipation (Note 3)	P _D	1.4	W
Thermal Resistance, Junction to Ambient @T _A = 25°C	$R_{ heta JA}$	90	°C/W
Operating and Storage Temperature Range	T _{J.} T _{STG}	-55 to +150	°C

Notes:

- 1. No purposefully added lead.
- 2. Diodes Inc.'s "Green" policy can be found on our website at http://www.diodes.com/products/lead_free/index.php.
- 3. Device mounted on FR-4 PCB with 2oz. Copper and test pulse width t ≤ 10s.
- 4. Repetitive rating, pulse width limited by junction temperature.

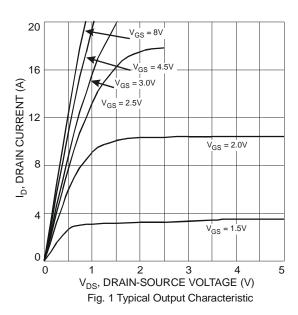


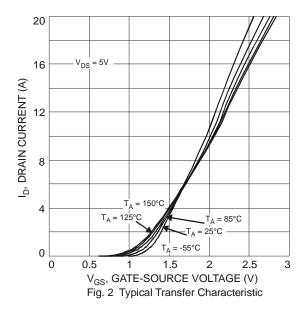
Electrical Characteristics @T_A = 25°C unless otherwise specified

Characteristic		Symbol	Min	Тур	Max	Unit	Test Condition
OFF CHARACTERISTICS (Note 5)							
Drain-Source Breakdown Voltage		BV _{DSS}	-20	_	_	V	$V_{GS} = 0V, I_D = -250\mu A$
Zero Gate Voltage Drain Current	$T_J = 25^{\circ}C$	I _{DSS}	_	_	-1.0	μΑ	$V_{DS} = -20V$, $V_{GS} = 0V$
Gate-Source Leakage		I_{GSS}	_	_	±100	nA	$V_{GS} = \pm 8V, V_{DS} = 0V$
ON CHARACTERISTICS (Note 5)							
Gate Threshold Voltage		V _{GS(th)}	-0.5	-	-0.9	V	$V_{DS} = V_{GS}$, $I_D = -250\mu A$
				45	60		$V_{GS} = -4.5V$, $I_D = -4.2A$
Static Drain-Source On-Resistance		R _{DS} (ON)	_	60	90	mΩ	$V_{GS} = -2.5V$, $I_{D} = -3.4A$
				87	113		$V_{GS} = -1.8V$, $I_D = -2.0A$
Forward Transfer Admittance		Y _{fs}	_	9	_	S	$V_{DS} = -5V, I_{D} = -4A$
DYNAMIC CHARACTERISTICS				<u>.</u>			_
Input Capacitance		C _{iss}	_	727	_	рF	V 00V V 0V
Output Capacitance		Coss	_	69	_	pF	$V_{DS} = -20V, V_{GS} = 0V$ -f = 1.0MHz
Reverse Transfer Capacitance		C _{rss}	_	64	_	pF	T = 1.0WH IZ
Gate Resistance		R_{G}		23		Ω	$V_{GS} = 0V, V_{DS} = 0V, f = 1.0MHz$
SWITCHING CHARACTERISTICS				<u>.</u>			_
Total Gate Charge		Q_{g}	_	7.6	_	nC	
Gate-Source Charge		Q_{gs}	_	1.4	_	nC	$V_{GS} = -4.5V$, $V_{DS} = -4V$, $I_{D} = -3.5A$
Gate-Drain Charge		Q_{gd}	_	1.2	_	nC	
Turn-On Delay Time		t _{D(on)}	_	14.0	_	ns	
Turn-On Rise Time		t _r	_	13.0	_	ns	$V_{DS} = -4V, V_{GS} = -4.5V,$
Turn-Off Delay Time		t _{D(off)}	_	53.8	_	ns	$R_L = 4\Omega$, $R_G = 6\Omega$, $I_D = -1A$
Turn-Off Fall Time	t _f	_	23.2	_	ns		

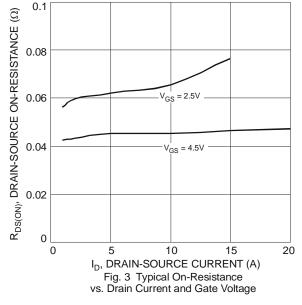
Notes:

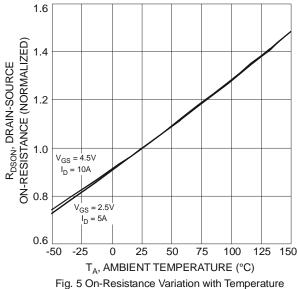
5. Short duration pulse test used to minimize self-heating effect.











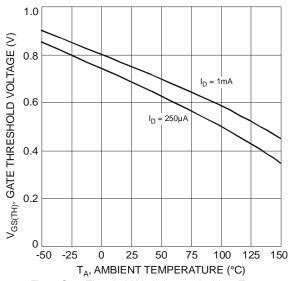


Fig. 7 Gate Threshold Variation vs. Ambient Temperature

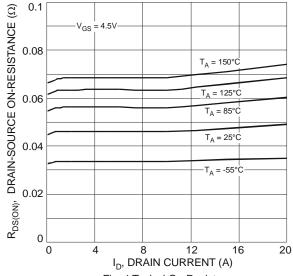


Fig. 4 Typical On-Resistance vs. Drain Current and Temperature

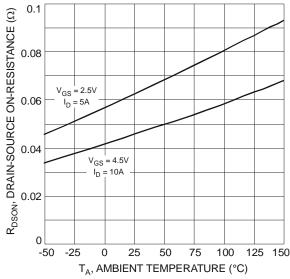
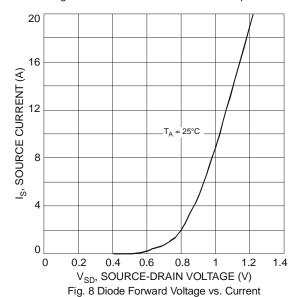
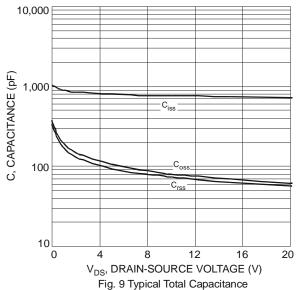


Fig. 6 On-Resistance Variation with Temperature







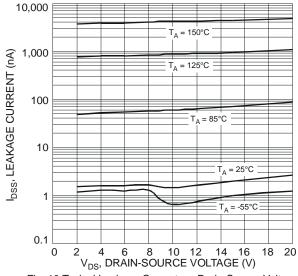
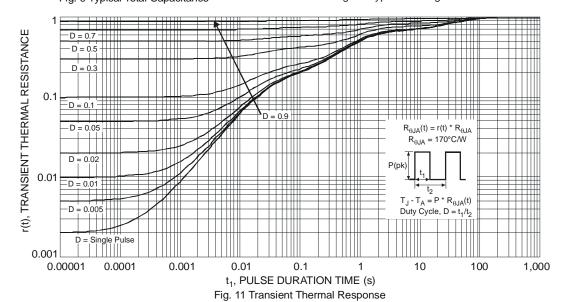


Fig. 10 Typical Leakage Current vs. Drain-Source Voltage

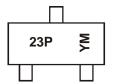


Ordering Information (Note 6)

Part Number	Case	Packaging
DMP2305U-7	SOT-23	3000/Tape & Reel

Notes: 6. For packaging details, go to our website at http://www.diodes.com/datasheets/ap02007.pdf.

Marking Information



23P = Product Type Marking Code YM = Date Code Marking Y = Year (ex: W = 2009)

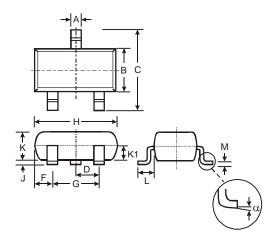
M = Month (ex: 9 = September)

Date Code Key

Year	200	9	2010		2011	20	12	2013		2014	2	2015
Code	W		Х		Υ	2	7	Α		В		С
Month	Jan	Feb	Mar	Apr	May	Jun	Jul	Aug	Sep	Oct	Nov	Dec
Code	1	2	3	4	5	6	7	8	9	0	N	D

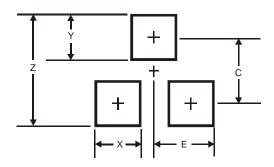


Package Outline Dimensions



SOT-23							
Dim	Min	Max	Тур				
Α	0.37	0.51	0.40				
В	1.20	1.40	1.30				
С	2.30	2.50	2.40				
D	0.89	1.03	0.915				
F	0.45	0.60	0.535				
G	1.78	2.05	1.83				
Н	2.80	3.00	2.90				
J	0.013	0.10	0.05				
K	0.903	1.10	1.00				
K1	-	-	0.400				
L	0.45	0.61	0.55				
M	0.085	0.18	0.11				
α	0°	8°	-				
All	All Dimensions in mm						

Suggested Pad Layout



Dimensions	Value (in mm)
Z	2.9
Х	0.8
Y	0.9
C	2.0
F	1 35



IMPORTANT NOTICE

DIODES INCORPORATED MAKES NO WARRANTY OF ANY KIND, EXPRESS OR IMPLIED, WITH REGARDS TO THIS DOCUMENT, INCLUDING, BUT NOT LIMITED TO, THE IMPLIED WARRANTIES OF MERCHANTABILITY AND FITNESS FOR A PARTICULAR PURPOSE (AND THEIR EQUIVALENTS UNDER THE LAWS OF ANY JURISDICTION).

Diodes Incorporated and its subsidiaries reserve the right to make modifications, enhancements, improvements, corrections or other changes without further notice to this document and any product described herein. Diodes Incorporated does not assume any liability arising out of the application or use of this document or any product described herein; neither does Diodes Incorporated convey any license under its patent or trademark rights, nor the rights of others. Any Customer or user of this document or products described herein in such applications shall assume all risks of such use and will agree to hold Diodes Incorporated and all the companies whose products are represented on Diodes Incorporated website, harmless against all damages.

Diodes Incorporated does not warrant or accept any liability whatsoever in respect of any products purchased through unauthorized sales channel. Should Customers purchase or use Diodes Incorporated products for any unintended or unauthorized application, Customers shall indemnify and hold Diodes Incorporated and its representatives harmless against all claims, damages, expenses, and attorney fees arising out of, directly or indirectly, any claim of personal injury or death associated with such unintended or unauthorized application.

Products described herein may be covered by one or more United States, international or foreign patents pending. Product names and markings noted herein may also be covered by one or more United States, international or foreign trademarks.

LIFE SUPPORT

Diodes Incorporated products are specifically not authorized for use as critical components in life support devices or systems without the express written approval of the Chief Executive Officer of Diodes Incorporated. As used herein:

- A. Life support devices or systems are devices or systems which:
 - 1. are intended to implant into the body, or
 - 2. support or sustain life and whose failure to perform when properly used in accordance with instructions for use provided in the labeling can be reasonably expected to result in significant injury to the user.
- B. A critical component is any component in a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or to affect its safety or effectiveness.

Customers represent that they have all necessary expertise in the safety and regulatory ramifications of their life support devices or systems, and acknowledge and agree that they are solely responsible for all legal, regulatory and safety-related requirements concerning their products and any use of Diodes Incorporated products in such safety-critical, life support devices or systems, notwithstanding any devices- or systems-related information or support that may be provided by Diodes Incorporated. Further, Customers must fully indemnify Diodes Incorporated and its representatives against any damages arising out of the use of Diodes Incorporated products in such safety-critical, life support devices or systems.

Copyright © 2009, Diodes Incorporated

www.diodes.com